

# SHINDENGEN

## 3 Phase Bridge Diode

Diode Module

**S15VT80**

**800V 15A**

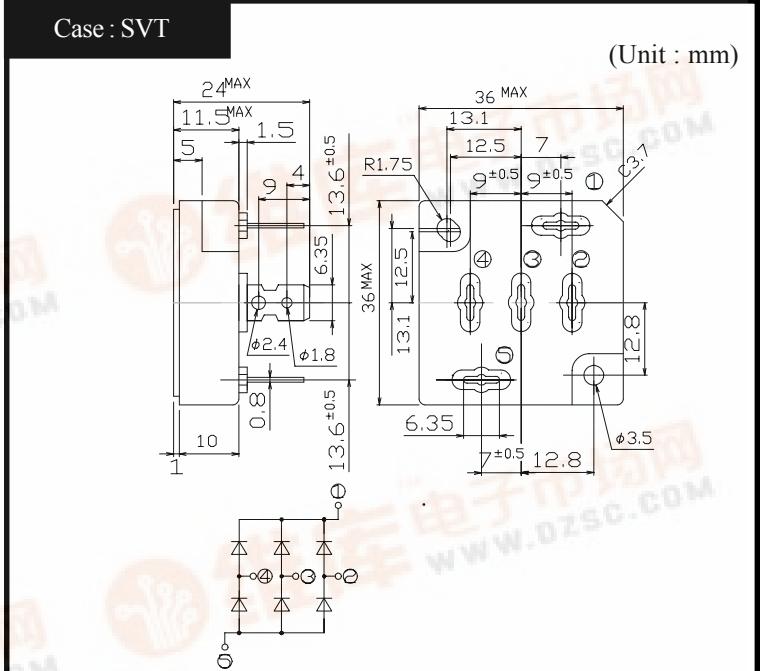
### FEATURES

- Dual In-Line Package
- Compact 3 phase bridge
- High IFSM
- Applicable to mount on glass-epoxy substrate (VTA type)

### APPLICATION

- Big Power Supply
- Air conditioner
- Factory Automation, Inverter

### OUTLINE DIMENSIONS



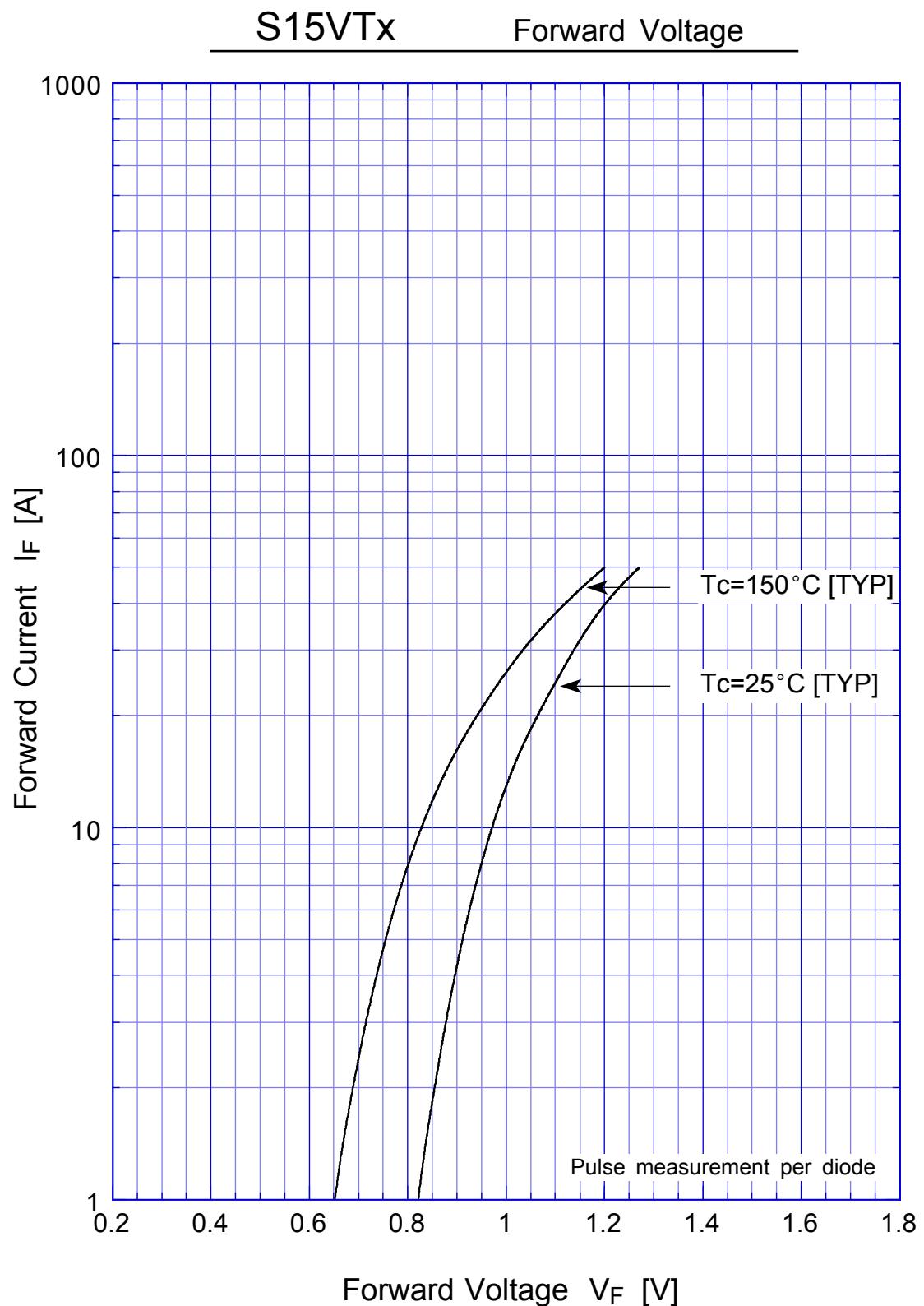
### RATINGS

#### ● Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$ )

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	$T_{stg}$		-40~150	°C
Operating Junction Temperature	$T_j$		150	°C
Maximum Reverse Voltage	$V_{RM}$		800	V
Average Rectified Forward Current	$I_O$	50Hz sine wave, R-load, With heatsink, $T_c=132^\circ\text{C}$	15	A
Peak Surge Forward Current	$I_{FSM}$	50Hz sine wave, Non-repetitive 1cycle peak value, Rating of per diode, $T_j=25^\circ\text{C}$	200	A
Current Squared Time	$I^2t$	1ms ≤ t < 10ms $T_c=25^\circ\text{C}$	160	$\text{A}^2\text{s}$
Dielectric Strength	$V_{dis}$	Terminals to case, AC 1 minute	2	kV
Mounting Torque	$T_{OR}$	(Recommended torque : 0.6N·m)	0.8	N·m

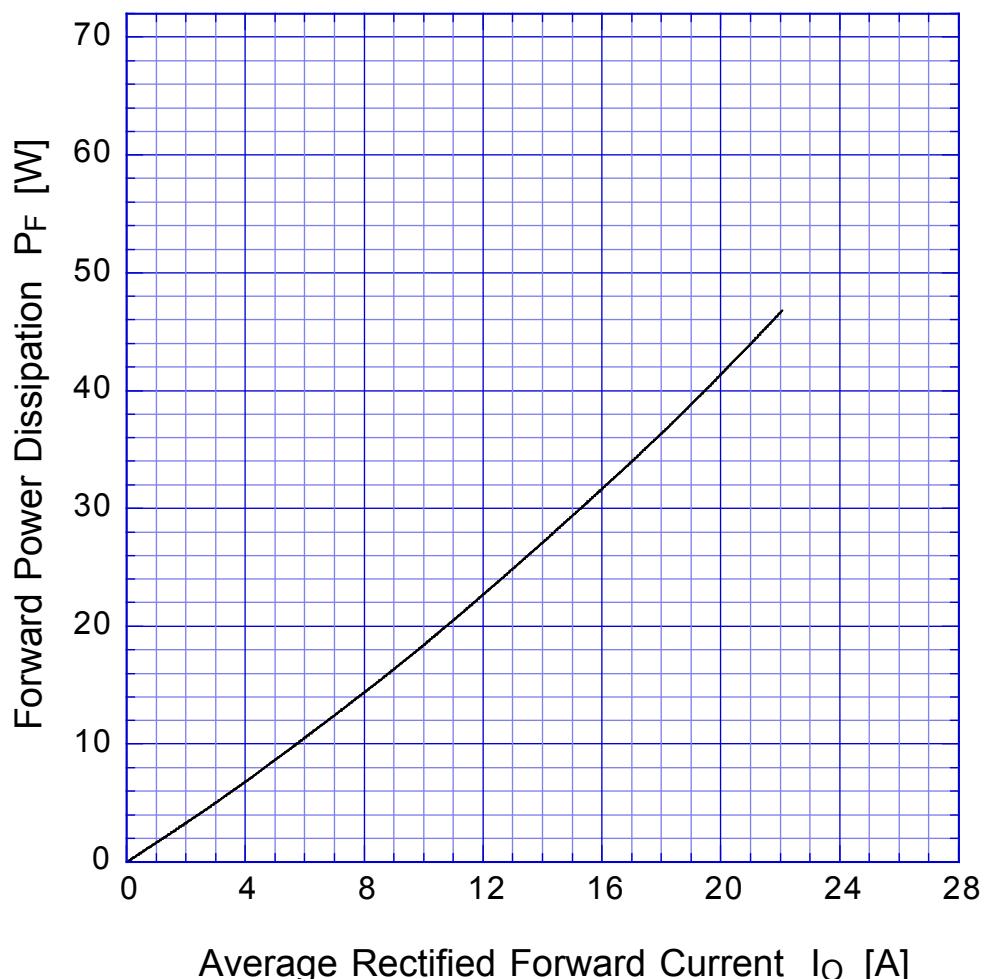
#### ● Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$ )

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	$V_F$	$I_F=5\text{A}$ , Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	$I_R$	$V_R=V_{RM}$ , Pulse measurement, Rating of per diode	Max.10	$\mu\text{A}$
Thermal Resistance	$\theta_{jc}$	junction to case	Max.0.6	$^\circ\text{C}/\text{W}$

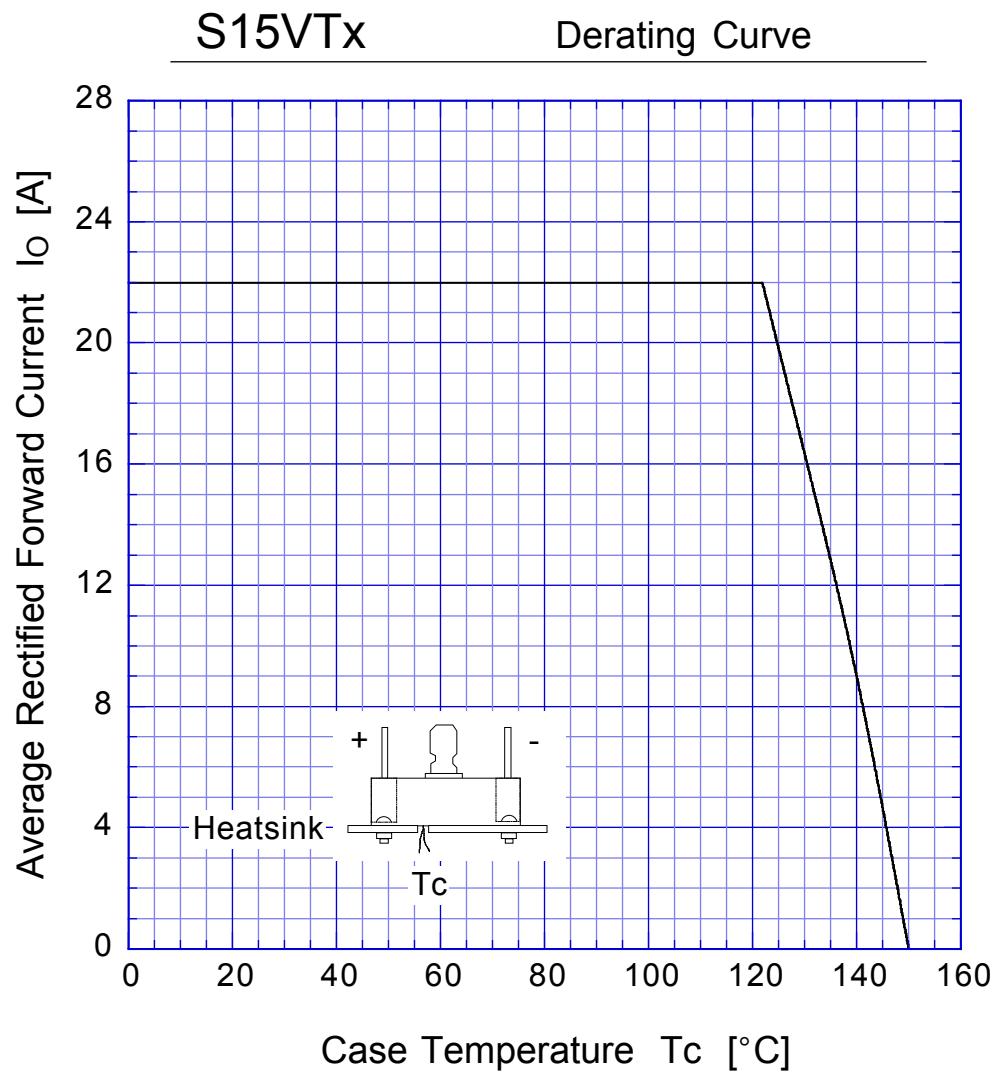


**S15VTx**

**Forward Power Dissipation**



$T_j = 150^\circ C$   
Sine wave



Sine wave  
R-load  
with heatsink

# S15VTx

## Peak Surge Forward Capability

